# **XP132A11A1SR**



ETR11007 002

#### **Power MOSFET**

## **■**GENERAL DESCRIPTION

The XP132A11A1SR is a P-channel Power MOSFET with low on-state resistance and ultra high-speed switching characteristics.

Because high-speed switching is possible, the IC can be efficiently set thereby saving energy.

The small SOP-8 package makes high density mounting possible.

## **■**APPLICATIONS

- Notebook PCs
- Cellular and portable phones
- On-board power supplies
- Li-ion battery systems

#### **■**FEATURES

**Low On-State Resistance** :  $Rds(on)=0.065 \Omega (Vgs=-10V)$ 

: Rds(on)=0.11  $\Omega$  (Vgs=-4.5V)

Ultra High-Speed Switching

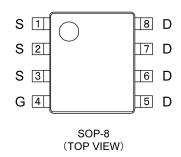
Driving Voltage : -4.5V

**P-Channel Power MOSFET** 

**DMOS Structure** 

Package : SOP-8

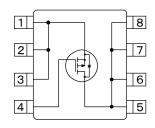
#### **■PIN CONFIGURATION**



## **■PIN ASSIGNMENT**

PIN NUMBER	PIN NAME	FUNCTION
1~3	S	Source
4	G	Gate
5~8	D	Drain

## **■**EQUIVALENT CIRCUIT



P-channel MOSFET (1 device built-in)

## ■ ABSOLUTE MAXIMUM RATINGS

Ta = 25°C

PARAMETER	SYMBOL	RATINGS	UNITS
Drain-Source Voltage	Vdss	-30	٧
Gate-Source Voltage	Vgss	±20	V
Drain Current (DC)	ld	-5	Α
Drain Current (Pulse)	ldp	-20	Α
Reverse Drain Current	ldr	-5	Α
Channel Power Dissipation *	Pd	2.5	W
Channel Temperature	Tch	150	လ
Storage Temperature Range	Tstg	-55~150	°C

<sup>\*</sup> When implemented on a glass epoxy PCB

## **■**ELECTRICAL CHARACTERISTICS

DC Characteristics Ta = 25°C

PARAMETER	SYMBOL	CONDITIONS	MIN.	TYP.	MAX.	UNITS
Drain Cut-Off Current	ldss	Vds=-30V, Vgs=0V	-	-	-10	μΑ
Gate-Source Leak Current	lgss	Vgs=±20V, Vds=0V	-	-	±1	μΑ
Gate-Source Cut-Off Voltage	Vgs(off)	Id=-1mA, Vds=-10V	-1.0	-	-2.5	V
Drain-Source On-State Resistance *	Rds(on)	Id=-3A, Vgs=-10V	-	0.055	0.065	Ω
		ld=-3A, Vgs=-4.5V	-	0.095	0.11	Ω
Forward Transfer Admittance *	Yfs	Id=-3A, Vds=-10V	-	6	-	S
Body Drain Diode Forward Voltage	Vf	If=-5A, Vgs=0V	-	-0.85	-1.1	V

<sup>\*</sup> Effective during pulse test.

## **Dynamic Characteristics**

Ta = 25°C

PARAMETER	SYMBOL	CONDITIONS	MIN.	TYP.	MAX.	UNITS
Input Capacitance	Ciss	Vds=-10V, Vgs=0V f=1MHz	-	680	-	pF
Output Capacitance	Coss		•	450	1	pF
Feedback Capacitance	Crss		-	170	-	pF

## **Switching Characteristics**

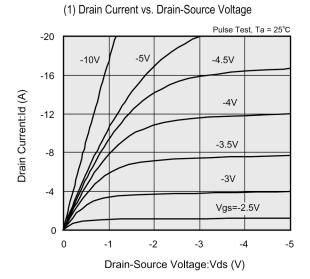
Ta = 25°C

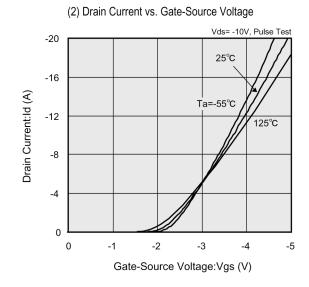
PARAMETER	SYMBOL	CONDITIONS	MIN.	TYP.	MAX.	UNITS
Turn-On Delay Time	td (on)	Vgs=-5V, Id=-3A Vdd=-10V	-	15	-	ns
Rise Time	tr		-	20	-	ns
Turn-Off Delay Time	td (off)		-	30	-	ns
Fall Time	tf		-	20	-	ns

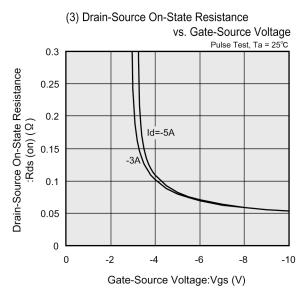
## Thermal Characteristics

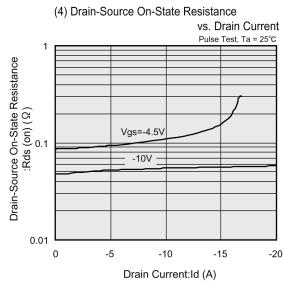
PARAMETER	SYMBOL	CONDITIONS	MIN.	TYP.	MAX.	UNITS
Thermal Resistance (Channel-Ambience)	Rth (ch-a)	Implement on a glass epoxy resin PCB	-	50	-	°C/W

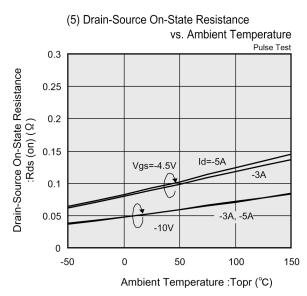
## ■TYPICAL PERFORMANCE CHARACTERISTICS

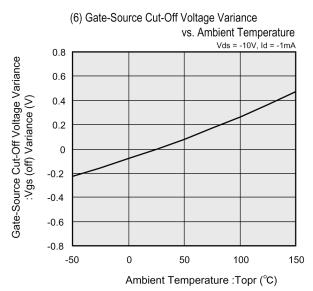




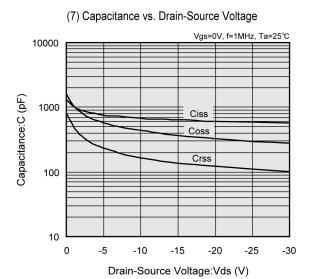


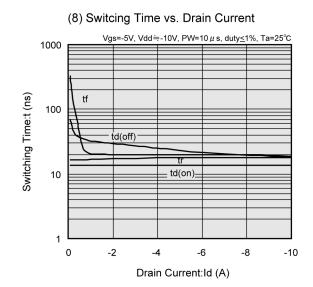


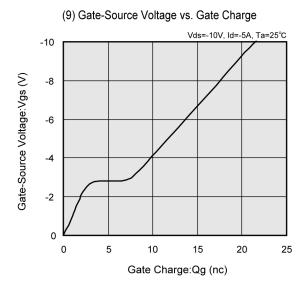


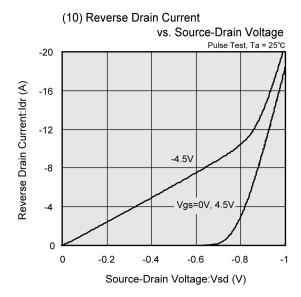


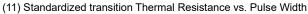
# ■TYPICAL PERFORMANCE CHARACTERISTICS (Continued)

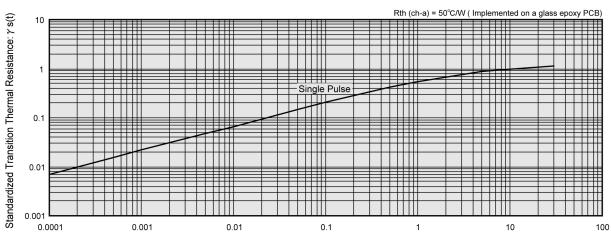












Pulse Width:PW (sec)

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